

21-24 Jun 2022



The 40th RD50 Workshop (CERN) Monolithic devices

CERN, 6/2-024 - BE Auditorium Meyrin

Friday 24 June

09:00

Monolithic devices

Session | Location: CERN, 6/2-024 - BE Auditorium Meyrin

09:00-09:20

DMAPS activities of the PSI high energy physics group

Speaker

Tilman Rohe

09:20-09:40

QFG transistors radiation damage effects

Speaker

Francisco Rogelio Palomo Pinto

09:40-10:00

Stitched Passive CMOS Strip Sensors

Speaker

Niels Sorgenfrei

10:00-10:20

Timing properties of the RD50-MPW2 HVCMOS chip

Speaker

Jernej Debevc

10:20-10:50

Coffee break

10:50-11:10

RD50-MPW3: General details and pixel matrix

Speaker

Chenfan Zhang

11:10-11:30

RD50-MPW3: Digital readout and DAQ developments

Speaker

Patrick Sieberer

11:30-11:50

Data Readout for Advanced Designs (DRAD), an update

Speaker

Francisco Rogelio Palomo Pinto

11:50-12:20 Discussion: Monolithic Devices

Speaker

Eva Vilella Figueras

12:20-12:40

Goodbye

Speaker

Michael Moll

12:40